



东沃电子
DOWOSEMI

SS32 thru SS320

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS	REVERSE VOLTAGE - 20 to 100 Volts FORWARD CURRENT - 3.0 Amperes																																																																																																																																	
FEATURES <ul style="list-style-type: none"> ● For surface mounted applications ● Metal-Semiconductor junction with guarding ● Epitaxial construction ● Very low forward voltage drop ● High current capability ● Plastic material has UL flammability classification 94V-0 ● For use in lowvoltage, high frequency inverters, free wheeling, and polarity protection applications. 	<p>SMA</p> <p>Dimensions in inches and (millimeters)</p>																																																																																																																																	
MECHANICAL DATA <ul style="list-style-type: none"> ● Case: Molded Plastic ● Polarity: Indicated by cathode band ● Weight: 0.002 ounces, 0.064 grams 																																																																																																																																		
MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS <p>Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%</p> <table border="1"> <thead> <tr> <th>CHARACTERISTICS</th><th>SYMBOL</th><th>SS32</th><th>SS33</th><th>SS34</th><th>SS35</th><th>SS36</th><th>SS310</th><th>SS320</th><th>UNIT</th></tr> </thead> <tbody> <tr> <td>Maximum Recurrent Peak Reverse Voltage</td><td>V_{RRM}</td><td>20</td><td>30</td><td>40</td><td>50</td><td>60</td><td>100</td><td>200</td><td>V</td></tr> <tr> <td>Maximum RMS Voltage</td><td>V_{RMS}</td><td>14</td><td>21</td><td>28</td><td>35</td><td>42</td><td>70</td><td>70</td><td>V</td></tr> <tr> <td>Maximum DC Blocking Voltage</td><td>V_{DC}</td><td>20</td><td>30</td><td>40</td><td>50</td><td>60</td><td>100</td><td>200</td><td>V</td></tr> <tr> <td>Maximum Average Forward Rectified Current @T_L=100 °C</td><td>I_(AV)</td><td colspan="6">3.0</td><td></td><td>A</td></tr> <tr> <td>Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed On Rated Load (JEDEC Method)</td><td>I_{FSM}</td><td colspan="6">80</td><td></td><td>A</td></tr> <tr> <td>Maximum Forward Voltage at 3.0A DC</td><td>V_F</td><td colspan="2">0.55</td><td colspan="2" rowspan="7">0.7</td><td colspan="2" rowspan="7">0.85</td><td></td><td>V</td></tr> <tr> <td>Maximum DC Reverse Current @T_J=25°C at Rated DC Blocking Voltage @T_J=100°C</td><td>I_R</td><td colspan="6">1.0 20</td><td></td><td>mA</td></tr> <tr> <td>Typical Junction Capacitance (Note1)</td><td>C_J</td><td colspan="6">250</td><td></td><td>pF</td></tr> <tr> <td>Typical Thermal Resistance (Note2)</td><td>R_{θJL}</td><td colspan="6">10</td><td></td><td>°C/W</td></tr> <tr> <td>Typical Thermal Resistance (Note3)</td><td>R_{θJA}</td><td colspan="6">50</td><td></td><td>°C/W</td></tr> <tr> <td>Operating Temperature Range</td><td>T_J</td><td colspan="6">-55 to + 125</td><td></td><td>°C</td></tr> <tr> <td>Storage Temperature Range</td><td>T_{STG}</td><td colspan="6">-55 to + 150</td><td></td><td>°C</td></tr> </tbody> </table> <p>NOTES:1.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC. 2.Thermal resistance junction to lead. 3.Thermal resistance junction to ambient.</p>	CHARACTERISTICS	SYMBOL	SS32	SS33	SS34	SS35	SS36	SS310	SS320	UNIT	Maximum Recurrent Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	100	200	V	Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	70	70	V	Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	100	200	V	Maximum Average Forward Rectified Current @T _L =100 °C	I _(AV)	3.0							A	Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed On Rated Load (JEDEC Method)	I _{FSM}	80							A	Maximum Forward Voltage at 3.0A DC	V _F	0.55		0.7		0.85			V	Maximum DC Reverse Current @T _J =25°C at Rated DC Blocking Voltage @T _J =100°C	I _R	1.0 20							mA	Typical Junction Capacitance (Note1)	C _J	250							pF	Typical Thermal Resistance (Note2)	R _{θJL}	10							°C/W	Typical Thermal Resistance (Note3)	R _{θJA}	50							°C/W	Operating Temperature Range	T _J	-55 to + 125							°C	Storage Temperature Range	T _{STG}	-55 to + 150							°C
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FIG. 1 - FORWARD CURRENT DERATING CURVE

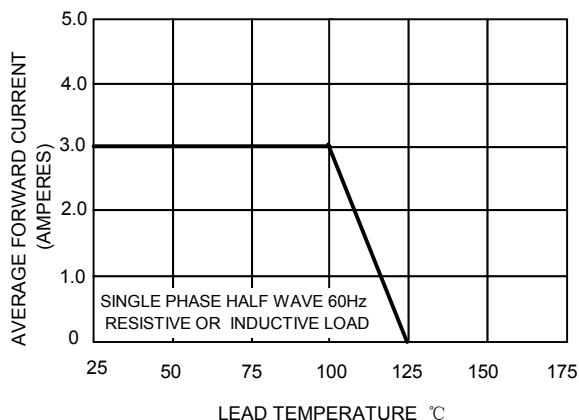


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

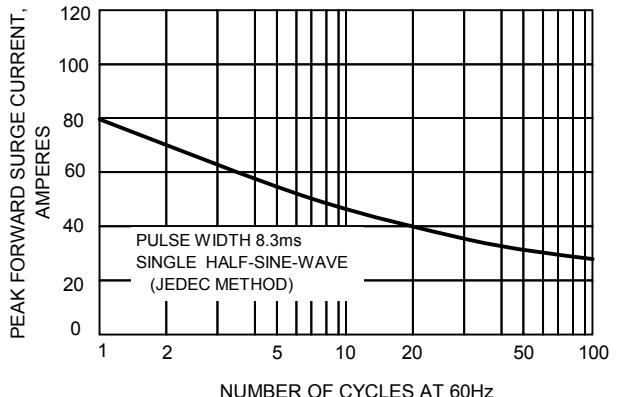


FIG.3-TYPICAL FORWARD CHARACTERISTICS

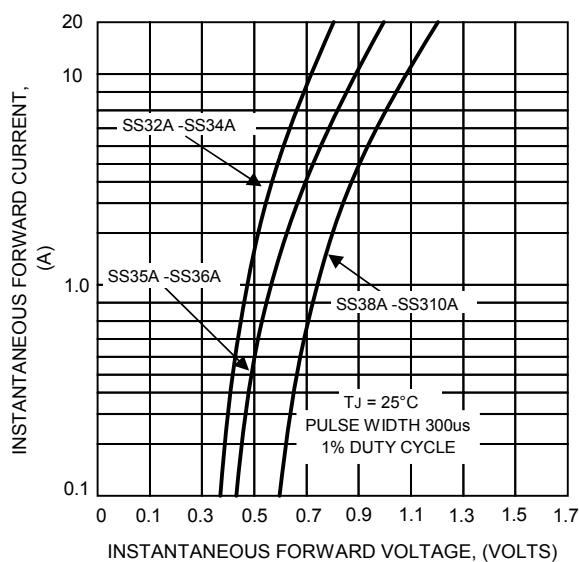


FIG.4-TYPICAL JUNCTION CAPACITANCE

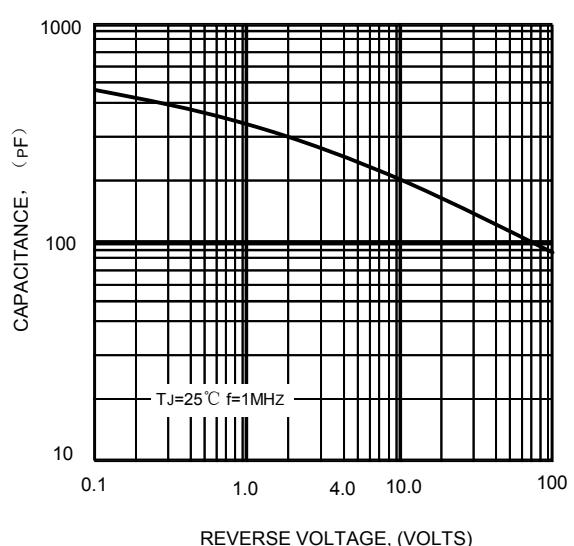
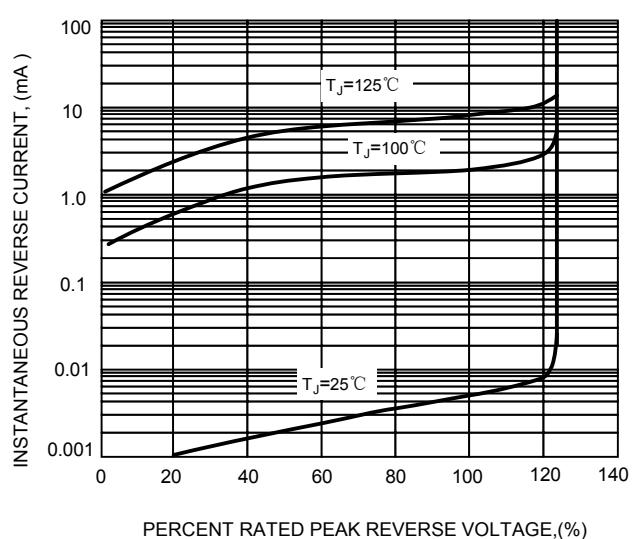


FIG.5-TYPICAL REVERSE CHARACTERISTICS



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